

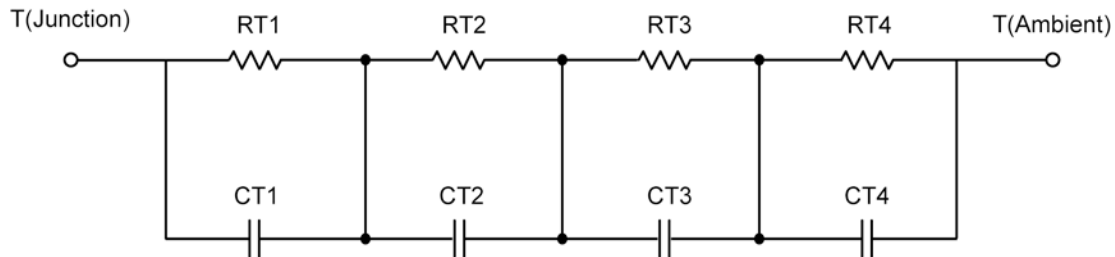
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

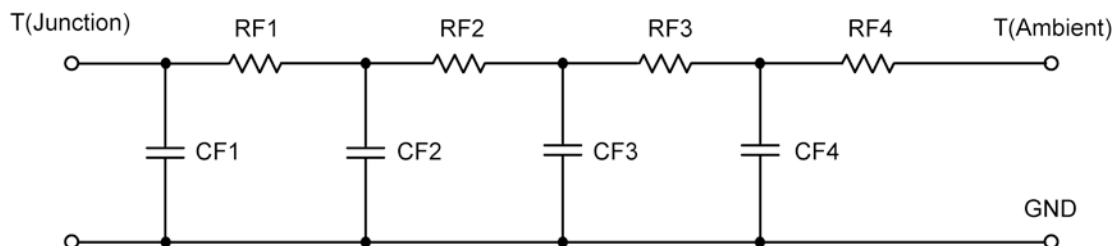
These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	64.0163	N/A	12.7602
RT2	5.1154	N/A	3.1537
RT3	46.1720	N/A	16.7148
RT4	50.6963	N/A	37.3713
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.3888	N/A	2.5036 m
CT2	137.7504 u	N/A	125.7713 u
CT3	24.3796 m	N/A	75.8127 m
CT4	2.2490 m	N/A	8.9659 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	8.2005	N/A	3.7905
RF2	53.7662	N/A	20.0274
RF3	37.4273	N/A	30.1322
RF4	66.6060	N/A	16.0499
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	152.5807 u	N/A	137.0612 u
CF2	2.0909 m	N/A	1.8875 m
CF3	16.8484 m	N/A	5.9845 m
CF4	1.1689	N/A	38.8486 m

Note

NA indicates not applicable

